

View Online at <https://aerobasegroup.com/nsn/5961-00-160-1805>

Inclosure Material:

Metal all semiconductor device diode

Overall Length:

0.735 inches all semiconductor device diode and 0.765 inches all semiconductor device diode

Overall Diameter:

0.215 inches all semiconductor device diode and 0.220 inches all semiconductor device diode

Function For Which Designed:

Microwave and mixer

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

4 semiconductor device diode

Mounting Method:

Press fit all semiconductor device diode

Features Provided:

Burn in

Semiconductor Material:

Silicon all semiconductor device diode

Current Rating Per Characteristic:

10.00 milliamperes forward current, dc all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air all semiconductor device diode

Special Features:

Two of the four diodes will be forward diodes and two will be reverse diodes

Precious Material:

Gold

Terminal Type And Quantity:

2 pin all semiconductor device diode

Specification Data:

18876-10658352 manufacturers source control

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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